TOSHIBA Photocoupler Photorelay

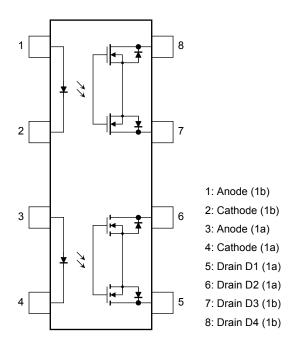
# **TLP4006G**

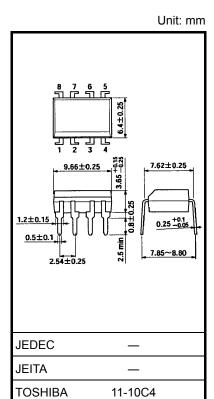
Telecommunication
Measurement Equipment
Security Equipment
FA

The Toshiba TLP4006G consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET and is the 1-form-A/B photorelay with 350-V withstanding voltage.

- Normally closed (1-form-B) device, normally opened (1-form-A) device
- Peak off-state voltage: 350 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 120 mA (max)
- On-state resistance:  $25 \Omega$  (max)
- Isolation voltage: 2500 Vrms (min)

## Pin Configuration (top view)





Weight: 0.54 g (typ.)

## Absolute Maximum Ratings (Ta = 25°C)

	Charact	Symbol	Rating	Unit	
	Forward current	lF	50	mA	
	Forward current derating (Ta	≥ 25°C)	ΔI <sub>F</sub> /°C	-0.5	mA/°C
LED	Peak forward current		I <sub>FP</sub>	1	Α
	Reverse voltage	V <sub>R</sub>	5	V	
	Junction temperature		Tj	125	°C
	Off-state output terminal volta	V <sub>OFF</sub>	350	V	
	On-state current	One channel operation			
Detector		Two channel operations (1a1b simultaneous operation)	ION	120	mA
Dete	0	One channel operation			
	On-state current derating (Ta ≥ 25°C)	Two channel operations (1a1b simultaneous operation)	Δl <sub>ON</sub> /°C	-1.2	mA/°C
	Junction temperature	Tj	125	°C	
Stora	age temperature range	T <sub>stg</sub>	-55 to 125	°C	
Oper	rating temperature range	T <sub>opr</sub>	-40 to 85	°C	
Lead	soldering temperature (10 s)	T <sub>sol</sub>	T <sub>sol</sub> 260		
Isola	tion voltage (AC, 1 min, R.H.	$BV_S$	2500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pins 1, 2, 3 and 4 are shorted together, and pins 5, 6, 7 and 8 are shorted together.

## **Recommended Operating Conditions**

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	$V_{DD}$	_	_	280	V
Forward current	lF	5	_	25	mA
On-state current	I <sub>ON</sub>	_	_	120	mA
Operating temperature	T <sub>opr</sub>	-20	_	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

#### **Electrical Characteristics (Ta = 25°C)**

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μА
	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz	_	30	_	pF
or	Off-state current	l <sub>OFF</sub>	V <sub>OFF</sub> = 350 V	_	_	1	μА
Detector	Capacitance (1b)	0	V = 0, f = 1 MHz, I <sub>F</sub> = 5 mA	_	65	_	, F
	Capacitance (1a)	C <sub>OFF</sub>	V = 0, f = 1 MHz	_	65	_	pF

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# **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristics	Form	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	1a	I <sub>FT</sub>	I <sub>ON</sub> = 120 mA		1	3	mA
ringger LLD current	1b	I <sub>FC</sub>	I <sub>OFF</sub> = 10 μA				IIIA
Return LED current	1a	I <sub>FC</sub>	I <sub>OFF</sub> = 10 μA	0.1			mA
Return LED Current	1b	I <sub>FT</sub>	I <sub>ON</sub> = 120 mA	1 0.1   —		_	III/A
On-state resistance (Note 2)	_	R <sub>ON</sub>	I <sub>ON</sub> = 120 mA	_	15	25	Ω

Note 2: 1-form-A:  $I_F = 5$  mA, 1-form-B:  $I_F = 0$  mA

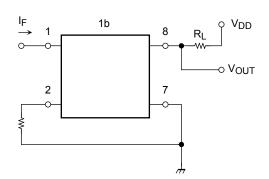
# **Isolation Characteristics (Ta = 25°C)**

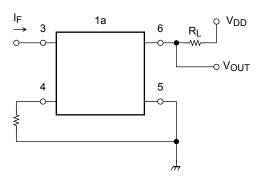
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	V <sub>S</sub> = 0, f = 1 MHz	_	8.0	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≤ 60%	$5 \times 10^{10}$	10 <sup>14</sup>	_	Ω
		AC, 1 min	2500	_	_	Vrms
Isolation voltage		AC, 1 s, in oil	_	5000	_	
		DC, 1 min, in oil	_	5000	_	Vdc

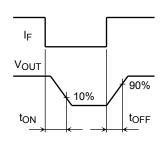
# **Switching Characteristics (Ta = 25°C)**

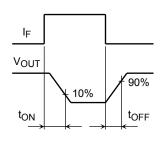
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
1b	Turn-on time	t <sub>ON</sub>	$R_L = 200 \Omega$	_	_	1	- ms
10	Turn-off time	toff	$V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$ (Note 3)	_	_	3	
1a	Turn-on time	ton	$R_L = 200 \Omega$	_		1	ms
Ia	Turn-off time	toff	$V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$ (Note 3)	_	_	1	1113

Note 3: Switching time test circuit

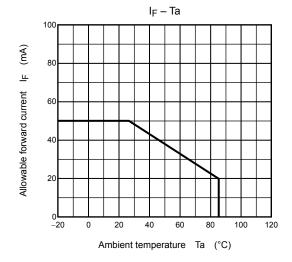


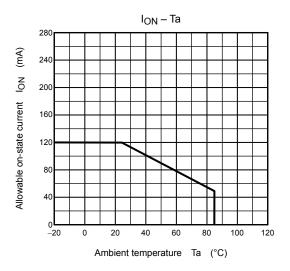


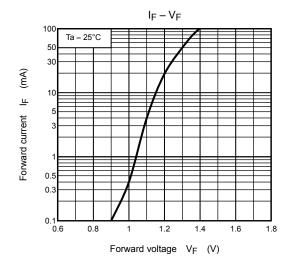




## Characteristics curves for 1-form-A/B

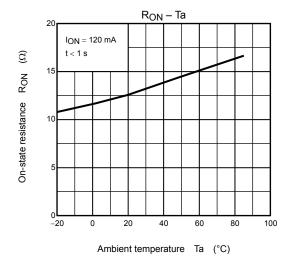


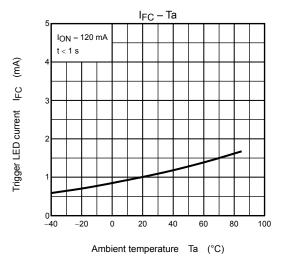


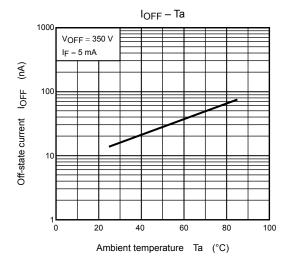


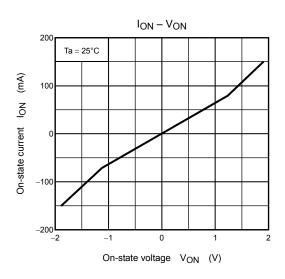
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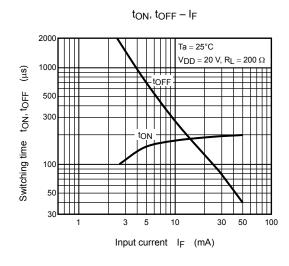
## Characteristics curves for 1-form-B

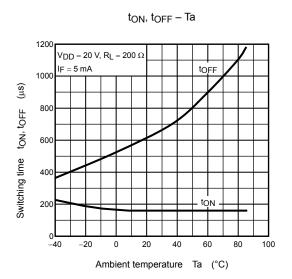




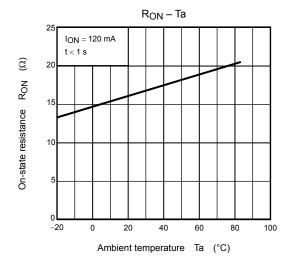


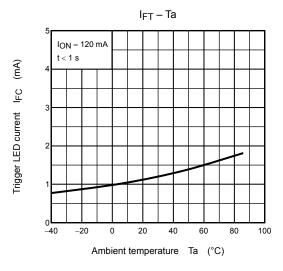


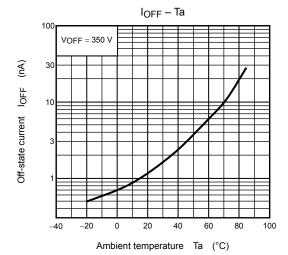


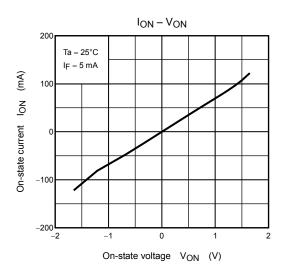


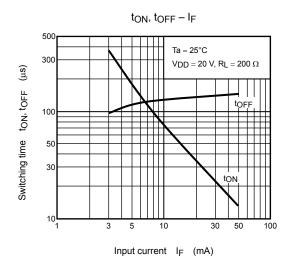
## Characteristics curves for 1-form-A

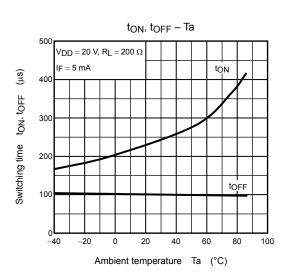












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